



SGM8291/SGM8292/SGM8294

High Voltage Rail-to-Rail Output Operational Amplifiers

GENERAL DESCRIPTION

The SGM8291 (single), SGM8292 (dual) and SGM8294 (quad) are high precision operational amplifiers, which are optimized for high voltage operation from 4.5V to 36V single supply or $\pm 2.25V$ to $\pm 18V$ dual power supplies. They provide a wide input common mode voltage range and rail-to-rail output voltage swing.

Furthermore, the SGM8291/2/4 provide high slew rate, low bias current, low offset current, low offset voltage and low offset voltage drift.

The SGM8291 is available in Green SOT-23-5, MSOP-8 and SOIC-8 packages. The SGM8292 is available in Green SOIC-8 and MSOP-8 packages. The SGM8294 is available in Green SOIC-14 and TSSOP-14 packages. They are specified over the extended -40°C to $+125^{\circ}\text{C}$ temperature range.

FEATURES

- Low Offset Voltage: 1.5mV (MAX)
- Low Input Bias Current
- Low Input Offset Current
- Wide Input Common Mode Voltage Range
- High Input Impedance
- Output Short-Circuit Protection
- Rail-to-Rail Output
- High Slew Rate: 7V/ μs
- Low Quiescent Current: 150 $\mu\text{A}/\text{Amplifier}$ (TYP)
- Small Packaging:

SGM8291 Available in Green SOT-23-5, MSOP-8 and SOIC-8 Packages

SGM8292 Available in Green MSOP-8 and SOIC-8 Packages

SGM8294 Available in Green SOIC-14 and TSSOP-14 Packages

APPLICATIONS

High Impedance Sensor
Photodiode Amplifier
Professional Audio Instrument
DAC Output Amplifier
Medical Equipment
Test Equipment
Active Filter
Precision Instrument

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8291	SOT-23-5	-40°C to +85°C	SGM8291AYN5G/TR	SCEXX	Tape and Reel, 3000
	SOT-23-5	-40°C to +85°C	SGM8291BYN5G/TR	SG6XX	Tape and Reel, 3000
	MSOP-8	-40°C to +85°C	SGM8291YMS8G/TR	SGM8291 YMS8 XXXXX	Tape and Reel, 3000
	SOIC-8	-40°C to +85°C	SGM8291YS8G/TR	SGM 8291YS8 XXXXX	Tape and Reel, 2500
SGM8292	MSOP-8	-40°C to +85°C	SGM8292YMS8G/TR	SGM8292 YMS8 XXXXX	Tape and Reel, 3000
	SOIC-8	-40°C to +85°C	SGM8292YS8G/TR	SGM 8292YS8 XXXXX	Tape and Reel, 2500
	SOIC-8	-40°C to +125°C	SGM8292XS8G/TR	SGM 8292XS8 XXXXX	Tape and Reel, 2500
SGM8294	SOIC-14	-40°C to +85°C	SGM8294YS14G/TR	SGM8294YS14 XXXXX	Tape and Reel, 2500
	TSSOP-14	-40°C to +85°C	SGM8294YTS14G/TR	SGM8294 YTS14 XXXXX	Tape and Reel, 3000
	TSSOP-14	-40°C to +125°C	SGM8294XTS14G/TR	SGM8294 XTS14 XXXXX	Tape and Reel, 3000

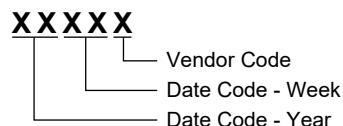
MARKING INFORMATION

NOTE: XX = Date Code. XXXXX = Date Code and Vendor Code.

SOT-23-5



SOIC-8/MSOP-8/SOIC-14/TSSOP-14



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, $+V_S$ to $-V_S$	40V
Input Common Mode Voltage Range	($-V_S$) - 0.1V to ($+V_S$) - 1.5V
Input/Output Voltage Range	($-V_S$) - 0.3V to ($+V_S$) + 0.3V
Differential Input Voltage.....	1.5V
Junction Temperature.....	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+260°C
ESD Susceptibility	
HBM.....	4000V
MM (SGM8291/2).....	150V
MM (SGM8294).....	200V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +125°C

NOTE:

1. It is recommended that CMOS device adopts the proper power supply sequence. Always sort the V_S first, followed by the inputs and outputs.

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

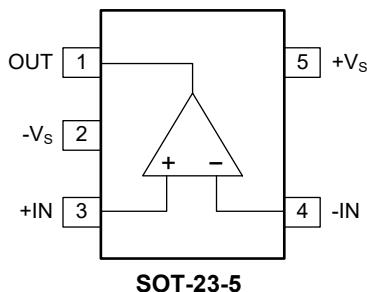
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

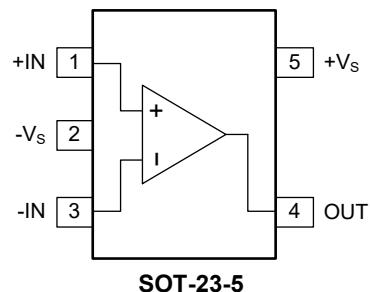
SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS

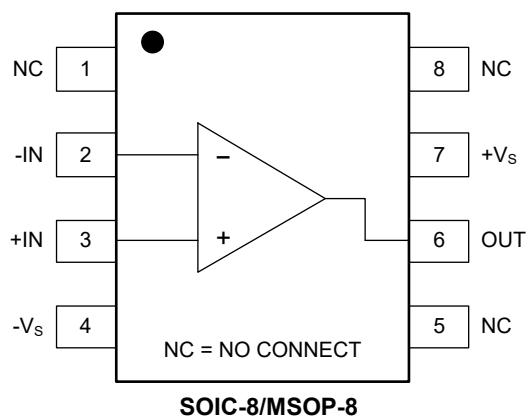
SGM8291AYN5G (TOP VIEW)



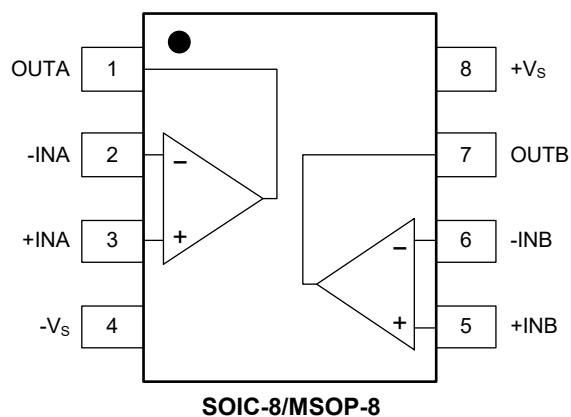
SGM8291BYN5G (TOP VIEW)



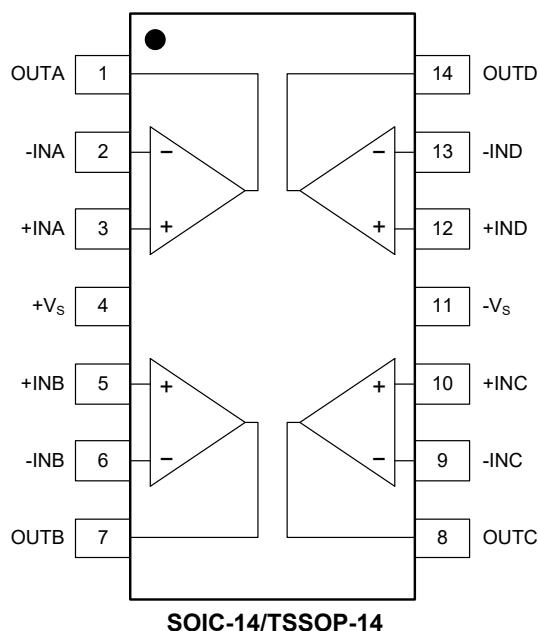
SGM8291 (TOP VIEW)



SGM8292 (TOP VIEW)



SGM8294 (TOP VIEW)



ELECTRICAL CHARACTERISTICS

($V_S = +5V$, $R_L = 2k\Omega$ connected to 2.5V, unless otherwise noted.)

PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE					
		+25°C	+25°C	-40°C to +85°C	-40°C to +125°C	UNITS	MIN/MAX	
Input Offset Voltage (V_{OS})	$V_{CM} = 2.5V$	0.3	1.5	2.4	2.75	mV	MAX	
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		3				$\mu V/\text{°C}$	TYP	
Input Bias Current (I_B)		20				pA	TYP	
Input Offset Current (I_{OS})		20				pA	TYP	
Open-Loop Voltage Gain (A_{OL})	$V_{OUT} = 0.5V$ to $4.5V$, $R_L = 5k\Omega$	86	75	72	70	dB	MIN	
Output Voltage Swing from Rail	V_{OH}	$R_L = 10k\Omega$	16	39	43	46	mV	MAX
	V_{OL}	$R_L = 10k\Omega$	14	30	34	38		
Output Short-Circuit Current (I_{SC})	Sink	$R_L = 10\Omega$	46.2	34.1	21.5	11.0	mA	MIN
	Source	$R_L = 10\Omega$	44.4	30.5	20.7	12.3		
Input Common Mode Voltage Range (V_{CM})		-0.1 to 3.5				V	TYP	
Common Mode Rejection Ratio (CMRR)	$V_{CM} = -0.1V$ to $3.5V$	84	67	62	60	dB	MIN	
Power Supply Rejection Ratio (PSRR)	$V_S = 4.5V$ to $36V$	103	82	80	78	dB	MIN	
Quiescent Current/Amplifier	$I_{OUT} = 0A$	144	275	309	329	μA	MAX	
Gain-Bandwidth Product (GBP)	$C_L = 100pF$, $V_{CM} = 2.5V$	1.4				MHz	TYP	
Gain Margin	$C_L = 100pF$, $V_{CM} = 2.5V$	-10				dB	TYP	
Phase Margin	$C_L = 100pF$, $V_{CM} = 2.5V$	50				°	TYP	
Channel-to-Channel Crosstalk	$f = 1MHz$	-80				dB	TYP	
Slew Rate (SR)	Up	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	5			$V/\mu s$	TYP	
	Down	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	5					
Overload Recovery Time (ORT)	Up	$V_{IN} \times G = V_S$	2.0			μs	TYP	
	Down	$V_{IN} \times G = V_S$	4.0					
Settling Time (t_s)	$C_L = 100pF$, $G = 1$, $200mV$ output step	2				μs	TYP	
Input Voltage Noise Density (e_n)	$f = 20kHz$, $V_{CM} = 2.5V$	30				nV/\sqrt{Hz}	TYP	
	$f = 1kHz$, $V_{CM} = 2.5V$	45						
Total Harmonic Distortion + Noise (THD+N)	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 600\Omega$	0.018				%	TYP	
	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 2k\Omega$	0.009						

ELECTRICAL CHARACTERISTICS (continued)

($V_S = \pm 5V$, $R_L = 2k\Omega$ connected to 0V, unless otherwise noted.)

PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE				
		+25°C	+25°C	-40°C to +85°C	-40°C to +125°C	UNITS	MIN/MAX
Input Offset Voltage (V_{OS})	$V_{CM} = 0V$	0.3	1.5	2.4	2.75	mV	MAX
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		3				$\mu V/\text{°C}$	TYP
Input Bias Current (I_B)		20				pA	TYP
Input Offset Current (I_{OS})		20				pA	TYP
Open-Loop Voltage Gain (A_{OL})	$V_{OUT} = -4.5V$ to $4.5V$, $R_L = 5k\Omega$	93	81	78	76	dB	MIN
Output Voltage Swing from Rail	V_{OH}	$R_L = 10k\Omega$	28	67	73	79	mV
	V_{OL}	$R_L = 10k\Omega$	23	39	47	62	
Output Current (I_{OUT})		60				mA	TYP
Input Common Mode Voltage Range (V_{CM})		-5.1 to 3.5				V	TYP
Common Mode Rejection Ratio (CMRR)	$V_{CM} = -5.1V$ to $3.5V$	92	75	68	66	dB	MIN
Quiescent Current/Amplifier	$I_{OUT} = 0A$	145	276	311	332	μA	MAX
Gain-Bandwidth Product (GBP)	$C_L = 100pF$, $V_{CM} = 0V$	1.4				MHz	TYP
Gain Margin	$C_L = 100pF$, $V_{CM} = 0V$	-10				dB	TYP
Phase Margin	$C_L = 100pF$, $V_{CM} = 0V$	50				°	TYP
Channel-to-Channel Crosstalk	$f = 1MHz$	-80				dB	TYP
Slew Rate (SR)	Up	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	6			V/ μs	TYP
	Down	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	4				
Overload Recovery Time (ORT)	Up	$V_{IN} \times G = V_S$	1.5			μs	TYP
	Down	$V_{IN} \times G = V_S$	2.5				
Settling Time (t_S)	$C_L = 100pF$, $G = 1$, 200mV output step	2				μs	TYP
Input Voltage Noise Density (e_n)	$f = 20kHz$, $V_{CM} = 0V$	30				$nV/\sqrt{\text{Hz}}$	TYP
	$f = 1kHz$, $V_{CM} = 0V$	45					
Total Harmonic Distortion + Noise (THD+N)	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 600\Omega$	0.018				%	TYP
	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 2k\Omega$	0.009					

ELECTRICAL CHARACTERISTICS (continued)

($V_S = \pm 15V$, $R_L = 2k\Omega$ connected to 0V, unless otherwise noted.)

PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE					
		+25°C	+25°C	-40°C to +85°C	-40°C to +125°C	UNITS	MIN/MAX	
Input Offset Voltage (V_{OS})	$V_{CM} = 0V$	0.3	1.5	2.4	2.75	mV	MAX	
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		3				$\mu V/^{\circ}C$	TYP	
Input Bias Current (I_B)		20				pA	TYP	
Input Offset Current (I_{OS})		20				pA	TYP	
Open-Loop Voltage Gain (A_{OL})	$V_{OUT} = -14.5V$ to $14.5V$, $R_L = 5k\Omega$	100	85	82	80	dB	MIN	
Output Voltage Swing from Rail	V_{OH}	$R_L = 10k\Omega$	67	174	193	210	mV	MAX
	V_{OL}	$R_L = 10k\Omega$	63	102	124	148		MAX
Output Current (I_{OUT})		60				mA	TYP	
Input Common Mode Voltage Range (V_{CM})		-15.1 to 13.5				V	TYP	
Common Mode Rejection Ratio (CMRR)	$V_{CM} = -15.1V$ to $13.5V$	95	79	71	66	dB	MIN	
Quiescent Current/Amplifier	$I_{OUT} = 0A$	150	286	320	337	μA	MAX	
Gain-Bandwidth Product (GBP)	$C_L = 100pF$, $V_{CM} = 0V$	1.4				MHz	TYP	
Gain Margin	$C_L = 100pF$, $V_{CM} = 0V$	-10				dB	TYP	
Phase Margin	$C_L = 100pF$, $V_{CM} = 0V$	50				°	TYP	
Channel-to-Channel Crosstalk	$f = 1MHz$	-80				dB	TYP	
Slew Rate (SR)	Up	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	7			V/ μ s	TYP	
	Down	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	4				TYP	
Overload Recovery Time (ORT)	Up	$V_{IN} \times G = V_S$	0.5			μ s	TYP	
	Down	$V_{IN} \times G = V_S$	1.0					
Settling Time (t_S)	$C_L = 100pF$, $G = 1$, 200mV output step	2				μ s	TYP	
Input Voltage Noise Density (e_n)	$f = 20kHz$, $V_{CM} = 0V$	29				nV/\sqrt{Hz}	TYP	
	$f = 1kHz$, $V_{CM} = 0V$	43						
Total Harmonic Distortion + Noise (THD+N)	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 600\Omega$	0.018				%	TYP	
	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 2k\Omega$	0.009						

ELECTRICAL CHARACTERISTICS (continued)

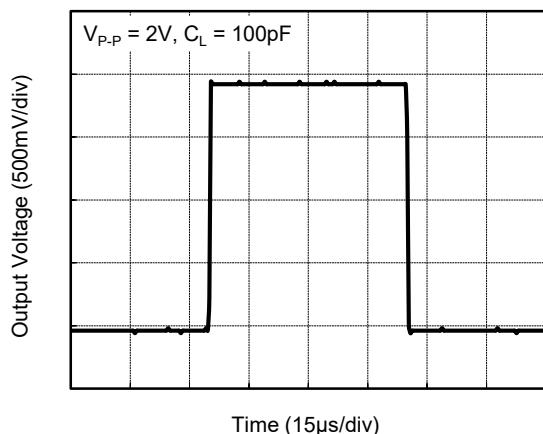
($V_S = \pm 18V$, $R_L = 2k\Omega$ connected to 0V, unless otherwise noted.)

PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATURE				
		+25°C	+25°C	-40°C to +85°C	-40°C to +125°C	UNITS	MIN/MAX
Input Offset Voltage (V_{OS})	$V_{CM} = 0V$	0.3	1.5	2.4	2.75	mV	MAX
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)		3				$\mu V/\text{°C}$	TYP
Input Bias Current (I_B)		20				pA	TYP
Input Offset Current (I_{OS})		20				pA	TYP
Open-Loop Voltage Gain (A_{OL})	$V_{OUT} = -17.5V$ to $17.5V$, $R_L = 5k\Omega$	101	87	84	82	dB	MIN
Output Voltage Swing from Rail	V_{OH}	$R_L = 10k\Omega$	81	208	231	251	mV
	V_{OL}	$R_L = 10k\Omega$	73	119	146	172	
Output Current (I_{OUT})		60				mA	TYP
Input Common Mode Voltage Range (V_{CM})		-18.1 to 16.5				V	TYP
Common Mode Rejection Ratio (CMRR)	$V_{CM} = -18.1V$ to $16.5V$	91	78	72	69	dB	MIN
Quiescent Current/Amplifier	$I_{OUT} = 0A$	157	299	332	352	μA	MAX
Gain-Bandwidth Product (GBP)	$C_L = 100pF$, $V_{CM} = 0V$	1.4				MHz	TYP
Gain Margin	$C_L = 100pF$, $V_{CM} = 0V$	-10				dB	TYP
Phase Margin	$C_L = 100pF$, $V_{CM} = 0V$	50				°	TYP
Channel-to-Channel Crosstalk	$f = 1MHz$	-80				dB	TYP
Slew Rate (SR)	Up	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	7			V/ μ s	TYP
	Down	$V_{OUT} = 2V_{P-P}$ step, $C_L = 100pF$, $G = 1$	4				TYP
Overload Recovery Time (ORT)	Up	$V_{IN} \times G = V_S$	0.5			μ s	TYP
	Down	$V_{IN} \times G = V_S$	1.0				
Settling Time (t_S)	$C_L = 100pF$, $G = 1$, 200mV output step	2				μ s	TYP
Input Voltage Noise Density (e_n)	$f = 20kHz$, $V_{CM} = 0V$	29				$nV/\sqrt{\text{Hz}}$	TYP
	$f = 1kHz$, $V_{CM} = 0V$	43					
Total Harmonic Distortion + Noise (THD+N)	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 600\Omega$	0.018				%	TYP
	$V_{OUT} = 2V_{P-P}$, $f = 1kHz$, $G = 1$, $R_L = 2k\Omega$	0.009					

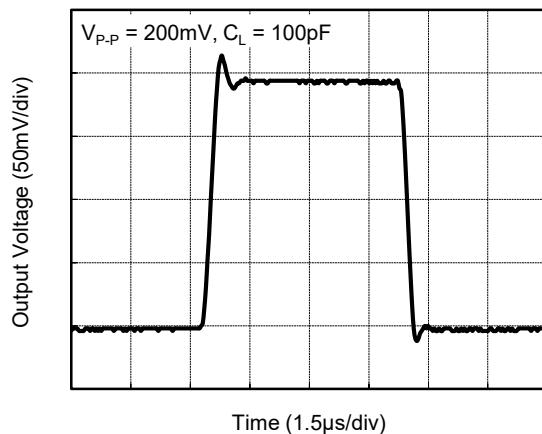
TYPICAL PERFORMANCE CHARACTERISTICS

At $T_A = +25^\circ\text{C}$, $V_s = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ connected to 0V, unless otherwise noted.

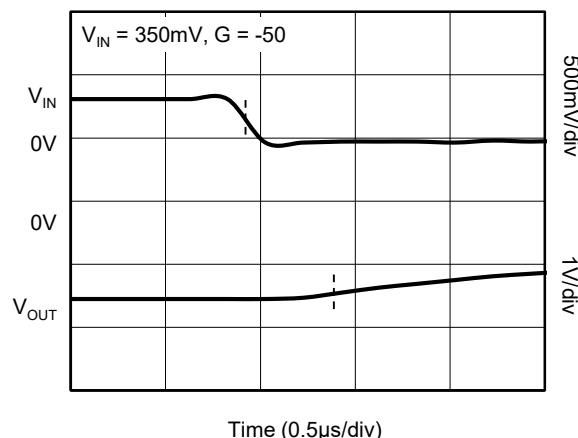
Large-Signal Step Response



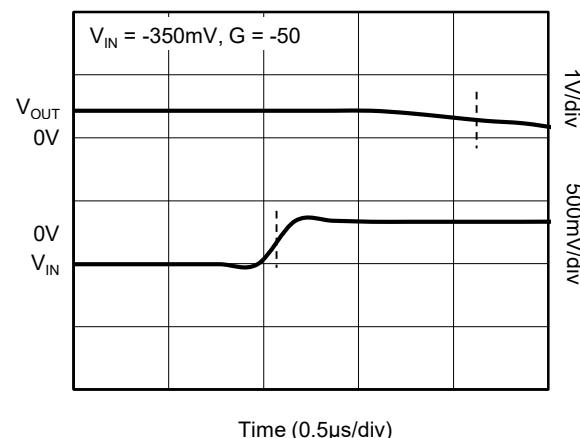
Small-Signal Step Response



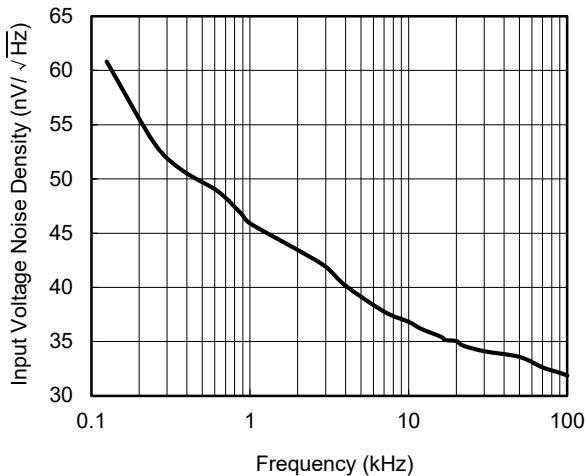
Negative Overload Recovery



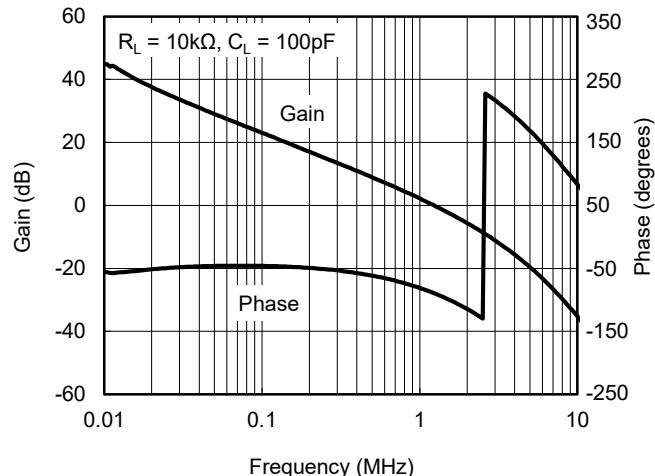
Positive Overload Recovery



Input Voltage Noise Density vs. Frequency

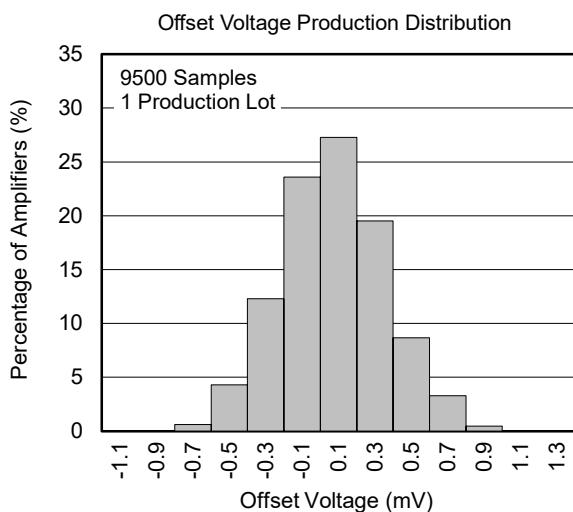


Gain and Phase vs. Frequency



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $V_s = \pm 15\text{V}$, $R_L = 2\text{k}\Omega$ connected to 0V, unless otherwise noted.



TYPICAL APPLICATION CIRCUITS

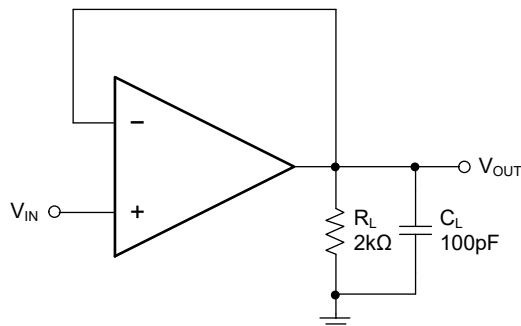


Figure 1

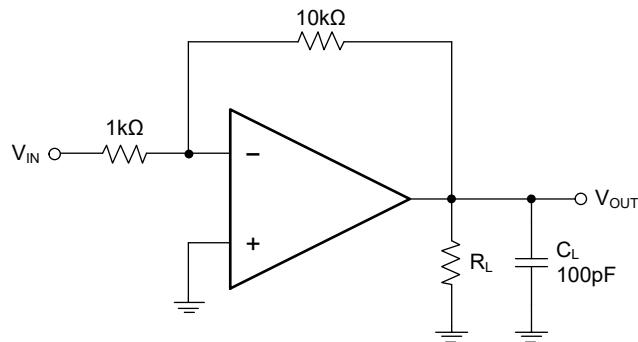


Figure 2

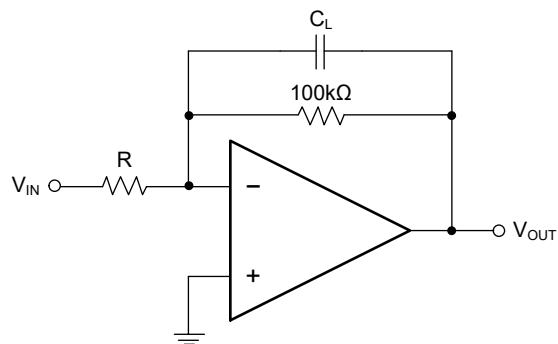


Figure 3

REVISION HISTORY

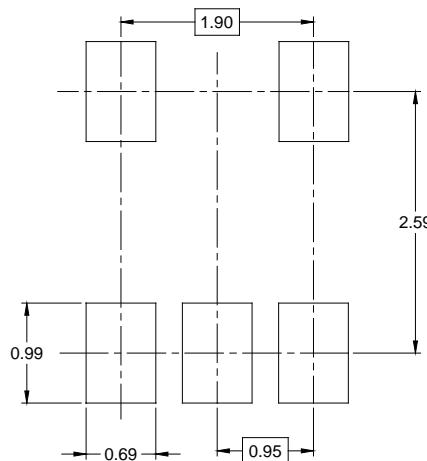
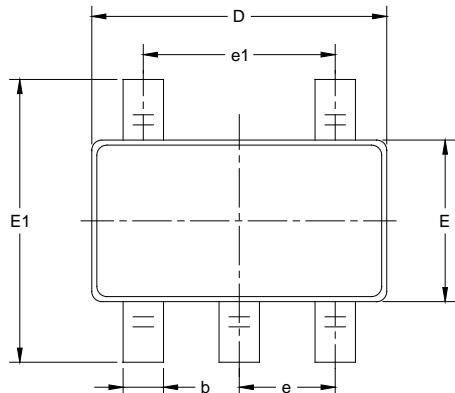
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

	Page
JULY 2024 – REV.A.2 to REV.A.3	
Added SGM8294XTS14G	2
JANUARY 2017 – REV.A.1 to REV.A.2	
Updated Absolute Maximum Ratings section.....	3
JANUARY 2016 – REV.A to REV.A.1	
Changed Electrical Characteristics section.....	6~8
Changed Package Outline Dimensions section	15~16
Changed Features section.....	1
Changes from Original (DECEMBER 2012) to REV.A	
Changed from product preview to production data.....	All

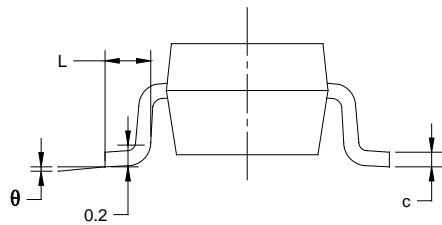
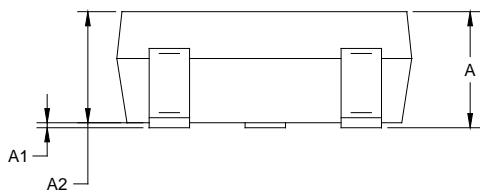
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOT-23-5



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

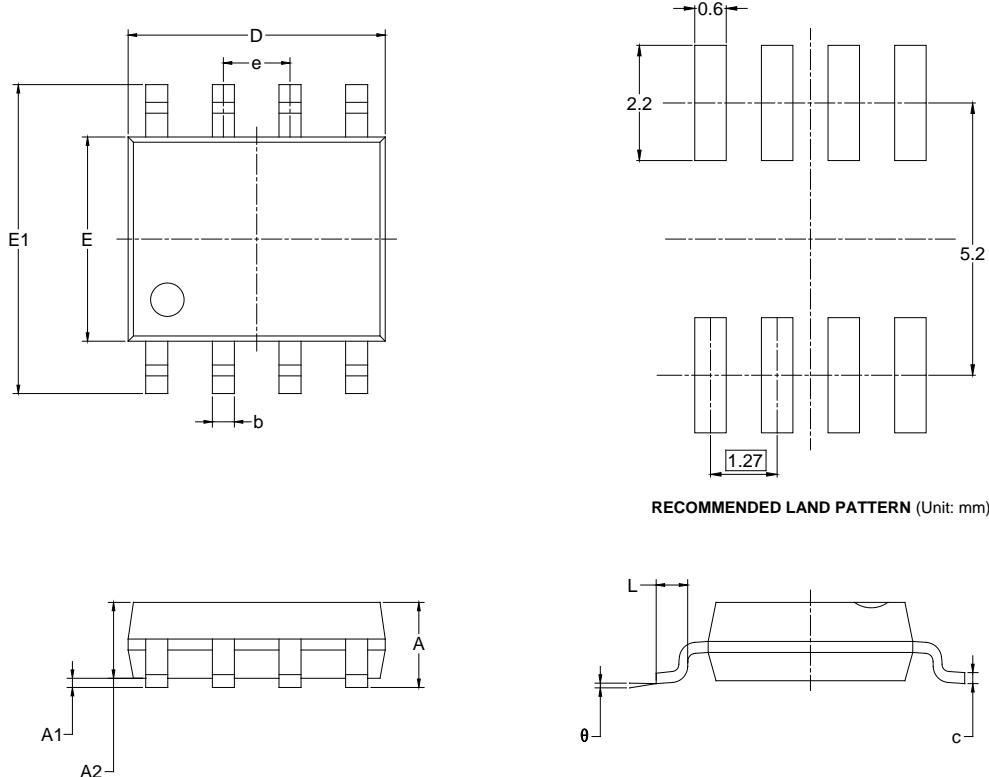
NOTES:

1. Body dimensions do not include mode flash or protrusion.
2. This drawing is subject to change without notice.

PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOIC-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

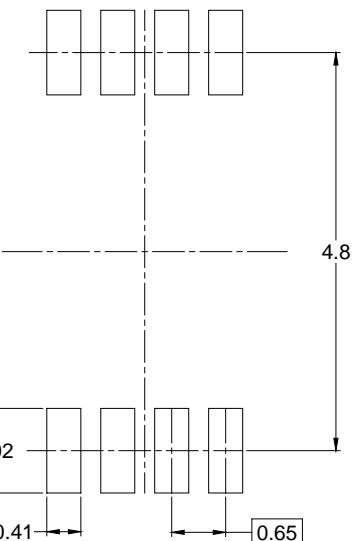
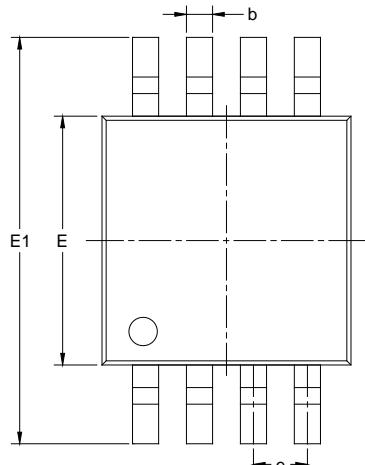
NOTES:

1. Body dimensions do not include mode flash or protrusion.
2. This drawing is subject to change without notice.

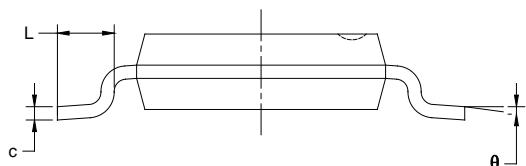
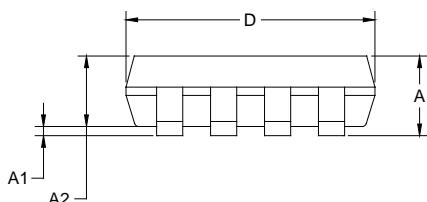
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

MSOP-8



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

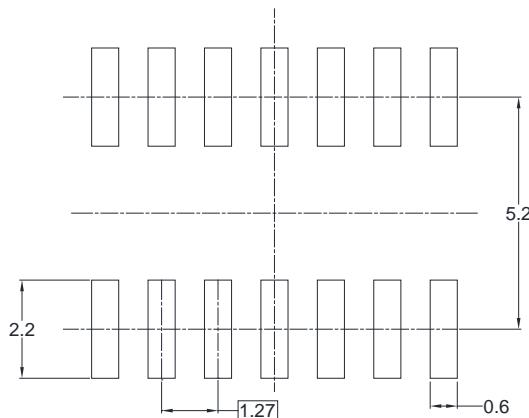
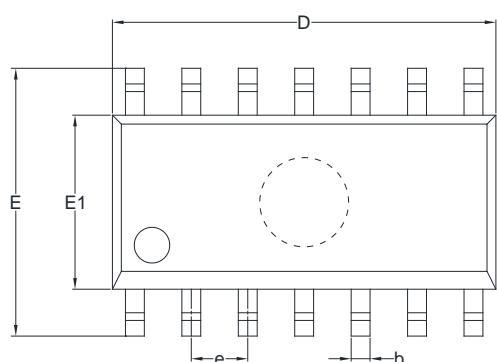
NOTES:

1. Body dimensions do not include mode flash or protrusion.
2. This drawing is subject to change without notice.

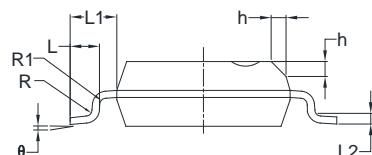
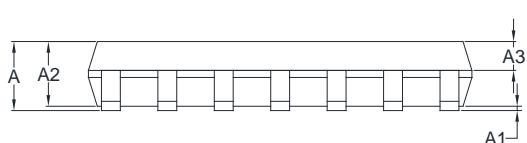
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

SOIC-14



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
A2	1.25	1.65	0.049	0.065
A3	0.55	0.75	0.022	0.030
b	0.36	0.49	0.014	0.019
D	8.53	8.73	0.336	0.344
E	5.80	6.20	0.228	0.244
E1	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
L	0.45	0.80	0.018	0.032
L1	1.04 REF		0.040 REF	
L2	0.25 BSC		0.01 BSC	
R	0.07		0.003	
R1	0.07		0.003	
h	0.30	0.50	0.012	0.020
θ	0°	8°	0°	8°

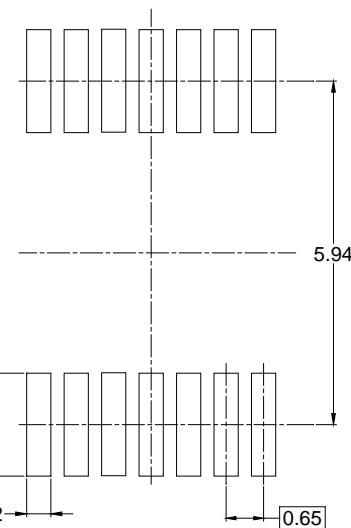
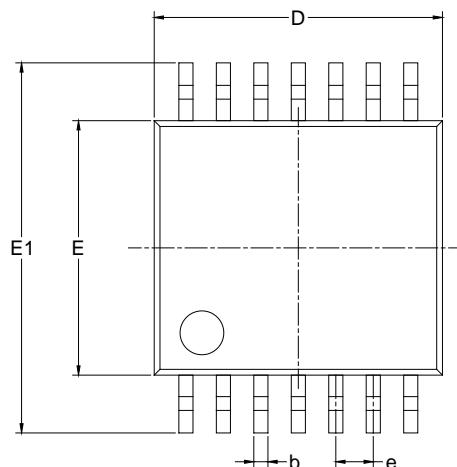
NOTES:

1. Body dimensions do not include mode flash or protrusion.
2. This drawing is subject to change without notice.

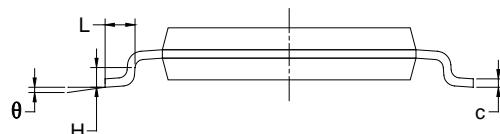
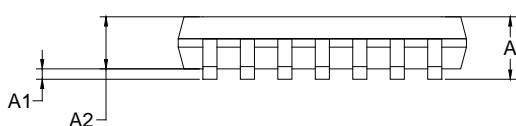
PACKAGE INFORMATION

PACKAGE OUTLINE DIMENSIONS

TSSOP-14



RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A		1.200		0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	4.860	5.100	0.191	0.201
E	4.300	4.500	0.169	0.177
E1	6.250	6.550	0.246	0.258
e	0.650 BSC		0.026 BSC	
L	0.500	0.700	0.02	0.028
H	0.25 TYP		0.01 TYP	
θ	1°	7°	1°	7°

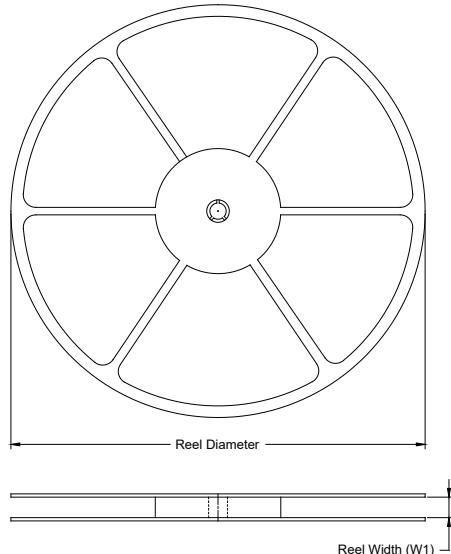
NOTES:

1. Body dimensions do not include mode flash or protrusion.
2. This drawing is subject to change without notice.

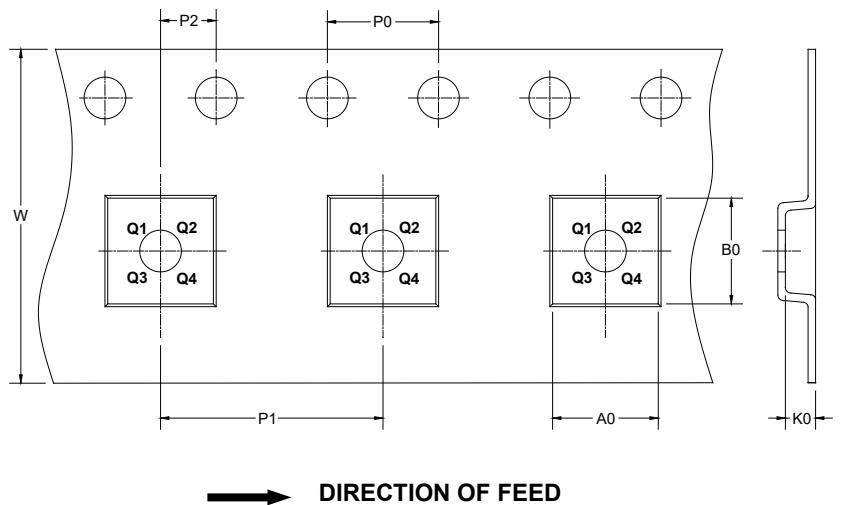
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



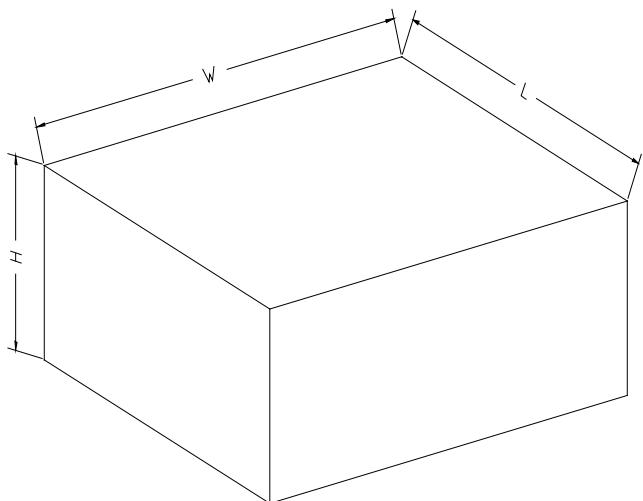
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1
SOIC-14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1
TSSOP-14	13"	12.4	6.80	5.40	1.50	4.0	8.0	2.0	12.0	Q1

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

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